NSN 5961-00-469-5160

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-469-5160 **Inclosure Material:** Ceramic **Overall Length:** 3.000 inches **Terminal Length:** 0.188 inches **Overall Height:** 0.750 inches **Overall Width:** 0.750 inches **End Application:** An/spg 53a radar **Mounting Facility Quantity: Mounting Method:** Terminal and unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20000.0 reverse voltage, peak **Current Rating Per Characteristic:** 100.00 milliamperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Encapsulated; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 turret **Specification Data:** 10001-2642262 manufacturers source control Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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